

MOSFETs Silicon N-channel MOS (U-MOS IV)

# TK80E06K3A

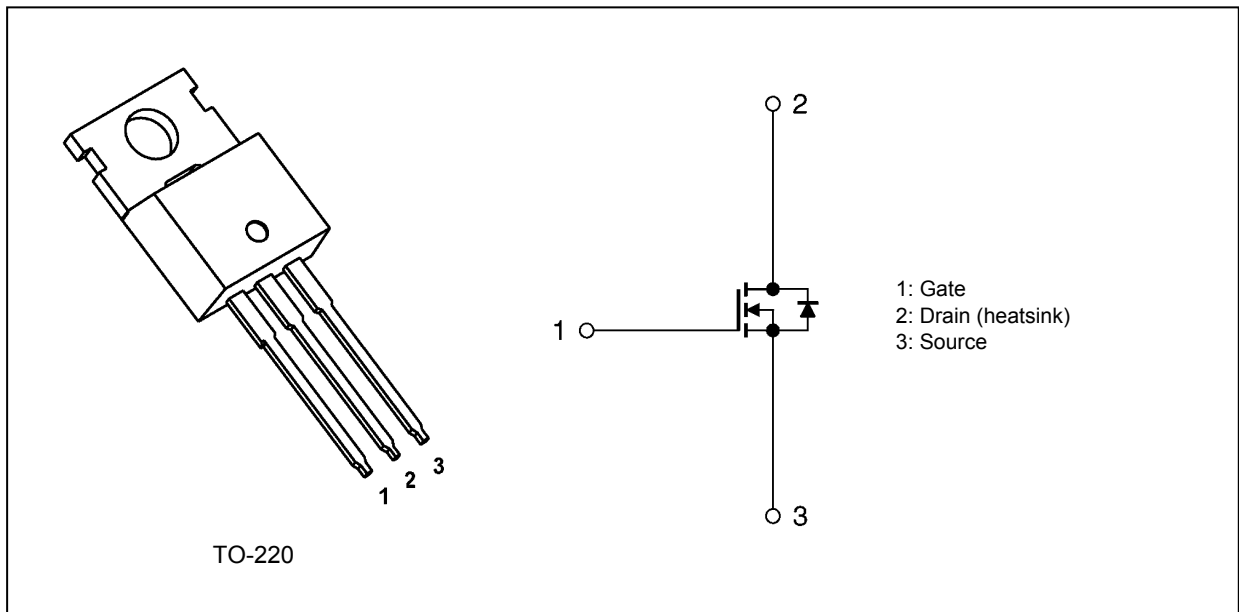
## 1. Applications

- Switching Voltage Regulators

## 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 4.8 \text{ m}\Omega$  (typ.)
- (2) Low leakage current:  $I_{DSS} = 10 \text{ }\mu\text{A}$  (max) ( $V_{DS} = 60 \text{ V}$ )
- (3) Enhancement mode:  $V_{th} = 3.0 \text{ to } 4.0 \text{ V}$  ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 1 \text{ mA}$ )

## 3. Packaging and Internal Circuit



## 4. Absolute Maximum Ratings (Note) ( $T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	60	V
Gate-source voltage	$V_{GSS}$	$\pm 20$	
Drain current (DC) (Note 1)	$I_D$	80	A
Drain current (pulsed) (Note 1)	$I_{DP}$	240	
Power dissipation ( $T_c = 25^\circ\text{C}$ )	$P_D$	125	W
Single-pulse avalanche energy (Note 2)	$E_{AS}$	76	mJ
Avalanche current	$I_{AR}$	80	A
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	$R_{th(ch-c)}$	1.00	°C/W
Channel-to-ambient thermal resistance	$R_{th(ch-a)}$	83.3	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD} = 25\text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$  (initial),  $L = 16.3\ \mu\text{H}$ ,  $R_G = 1.2\ \Omega$ ,  $I_{AR} = 80\text{ A}$

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

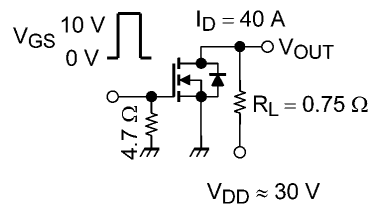
**6. Electrical Characteristics**

**6.1. Static Characteristics ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	—	—	$\pm 1$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = 60\text{ V}, V_{GS} = 0\text{ V}$	—	—	10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	60	—	—	V
	$V_{(BR)DSX}$	$I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$	35	—	—	
Gate threshold voltage	$V_{th}$	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	3.0	—	4.0	
Drain-source on-resistance	$R_{DS(ON)}$	$V_{GS} = 10\text{ V}, I_D = 40\text{ A}$	—	4.8	5.8	$\text{m}\Omega$

**6.2. Dynamic Characteristics ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	$C_{iss}$	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	4500	—	$\mu\text{F}$
Reverse transfer capacitance	$C_{rss}$		—	600	—	
Output capacitance	$C_{oss}$		—	800	—	
Switching time (rise time)	$t_r$	See Figure 6.2.1.	—	26	—	ns
Switching time (turn-on time)	$t_{on}$		—	56	—	
Switching time (fall time)	$t_f$		—	26	—	
Switching time (turn-off time)	$t_{off}$		—	74	—	



Duty  $\leq 1\%$ ,  $t_w = 10\ \mu\text{s}$

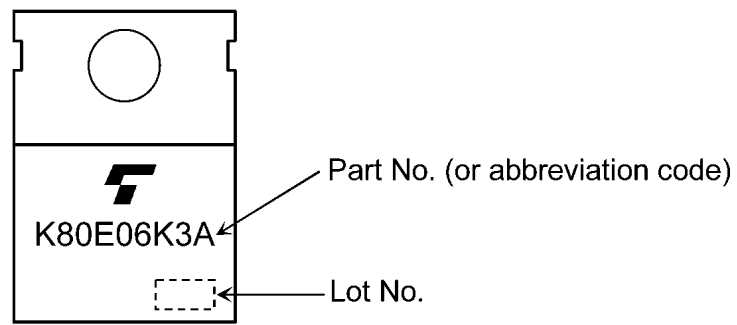
**Fig. 6.2.1 Switching Time Test Circuit**

**6.3. Gate Charge Characteristics ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

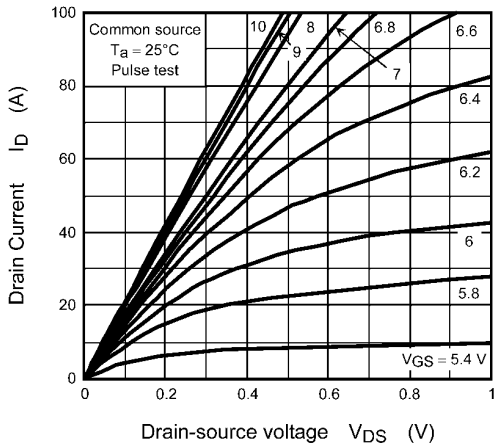
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx 48\text{ V}, V_{GS} = 10\text{ V}, I_D = 80\text{ A}$	—	90	—	nC
Gate-source charge 1	$Q_{gs1}$		—	27	—	
Gate-drain charge	$Q_{gd}$		—	37	—	

**6.4. Source-Drain Characteristics ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

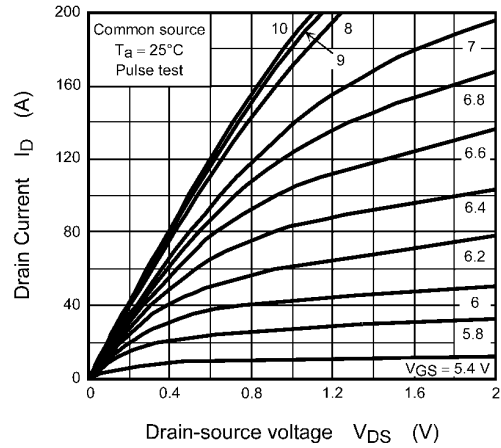
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (DC) (Note 1)	$I_{DR}$	—	—	—	80	A
Reverse drain current (pulsed) (Note 1)	$I_{DRP}$	—	—	—	240	
Diode forward voltage	$V_{DSF}$	$I_{DR} = 80\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.2	V
Reverse recovery time	$t_{rr}$	$I_{DR} = 80\text{ A}, V_{GS} = 0\text{ V}$ $-dI_{DR}/dt = 100\text{ A}/\mu\text{s}$	—	44	—	ns
Reverse recovery charge	$Q_{rr}$		—	66	—	nC

**7. Marking****Fig. 7.1 Marking**

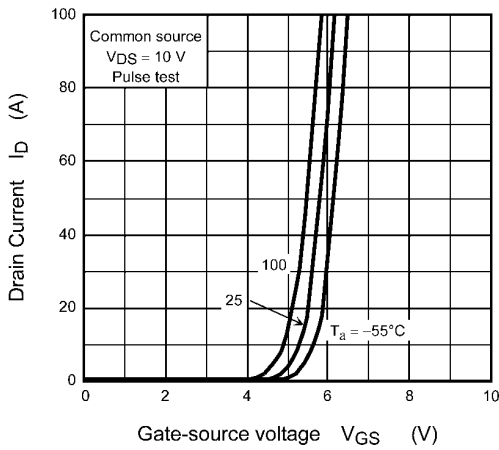
**8. Characteristics Curves (Note)**



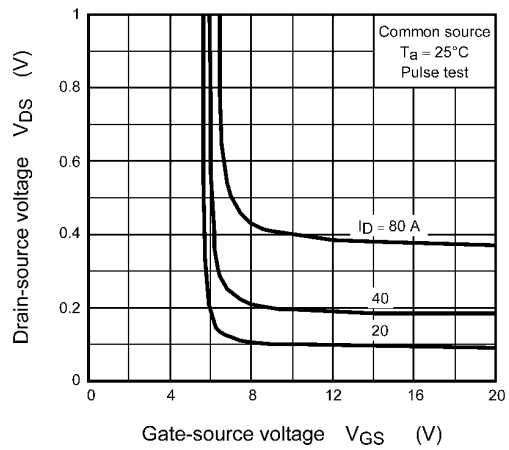
**Fig. 8.1  $I_D - V_{DS}$**



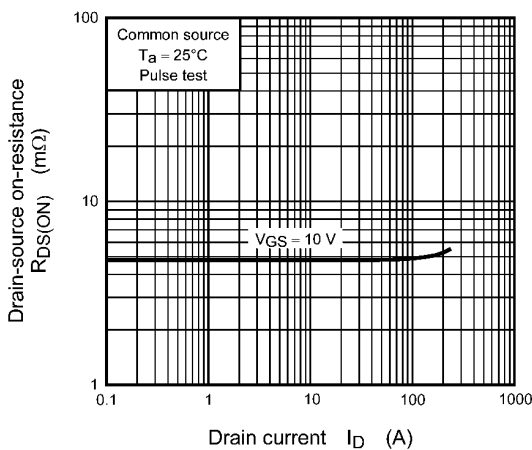
**Fig. 8.2  $I_D - V_{DS}$**



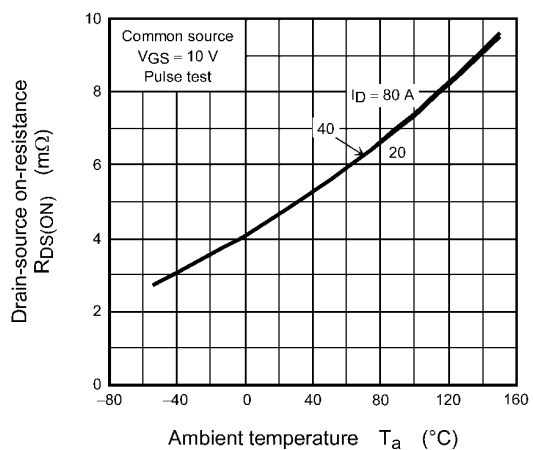
**Fig. 8.3  $I_D - V_{GS}$**



**Fig. 8.4  $V_{DS} - V_{GS}$**



**Fig. 8.5  $R_{DS(ON)} - I_D$**



**Fig. 8.6  $R_{DS(ON)} - T_a$**

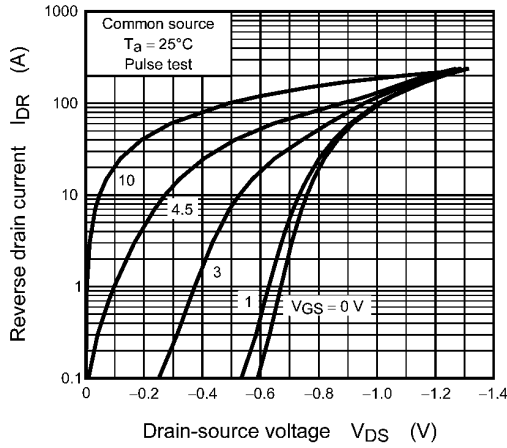


Fig. 8.7  $I_{DR} - V_{DS}$

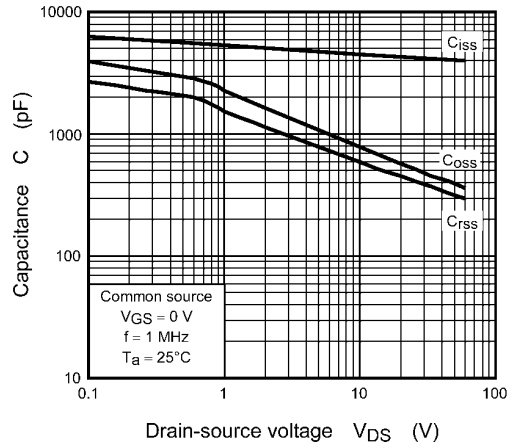


Fig. 8.8  $C - V_{DS}$

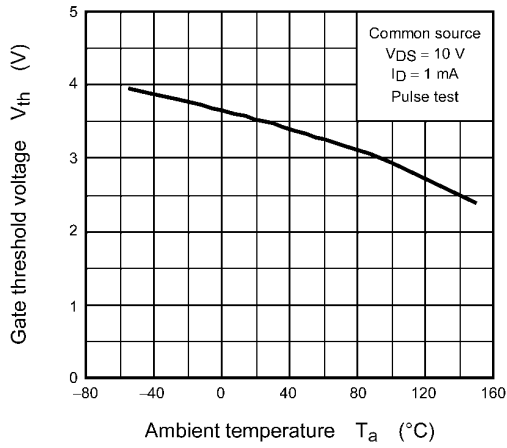


Fig. 8.9  $V_{th} - T_a$

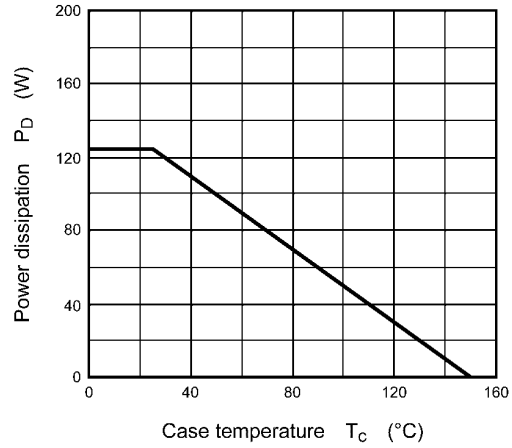


Fig. 8.10  $P_D - T_c$   
 (Guaranteed Maximum)

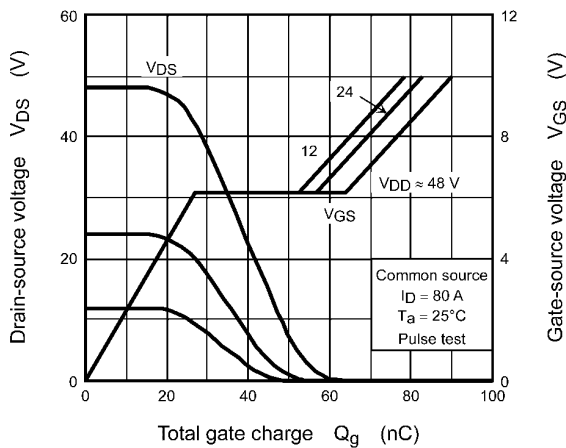
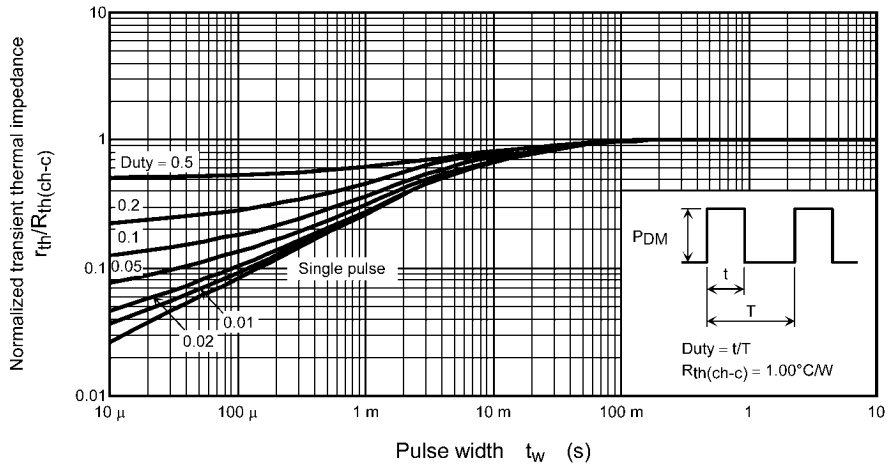
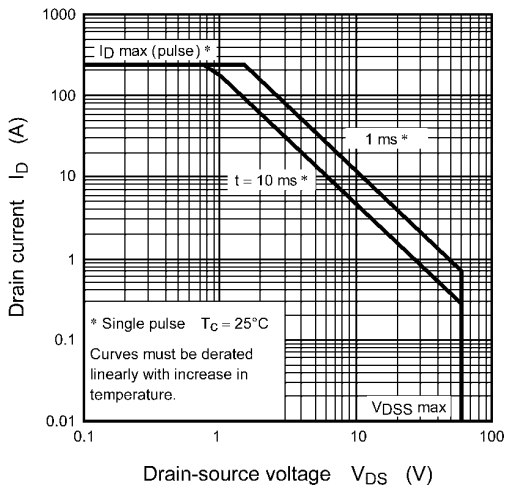


Fig. 8.11 Dynamic Input/Output Characteristics



**Fig. 8.12  $r_{th}/R_{th(ch-c)} - t_w$   
(Guaranteed Maximum)**

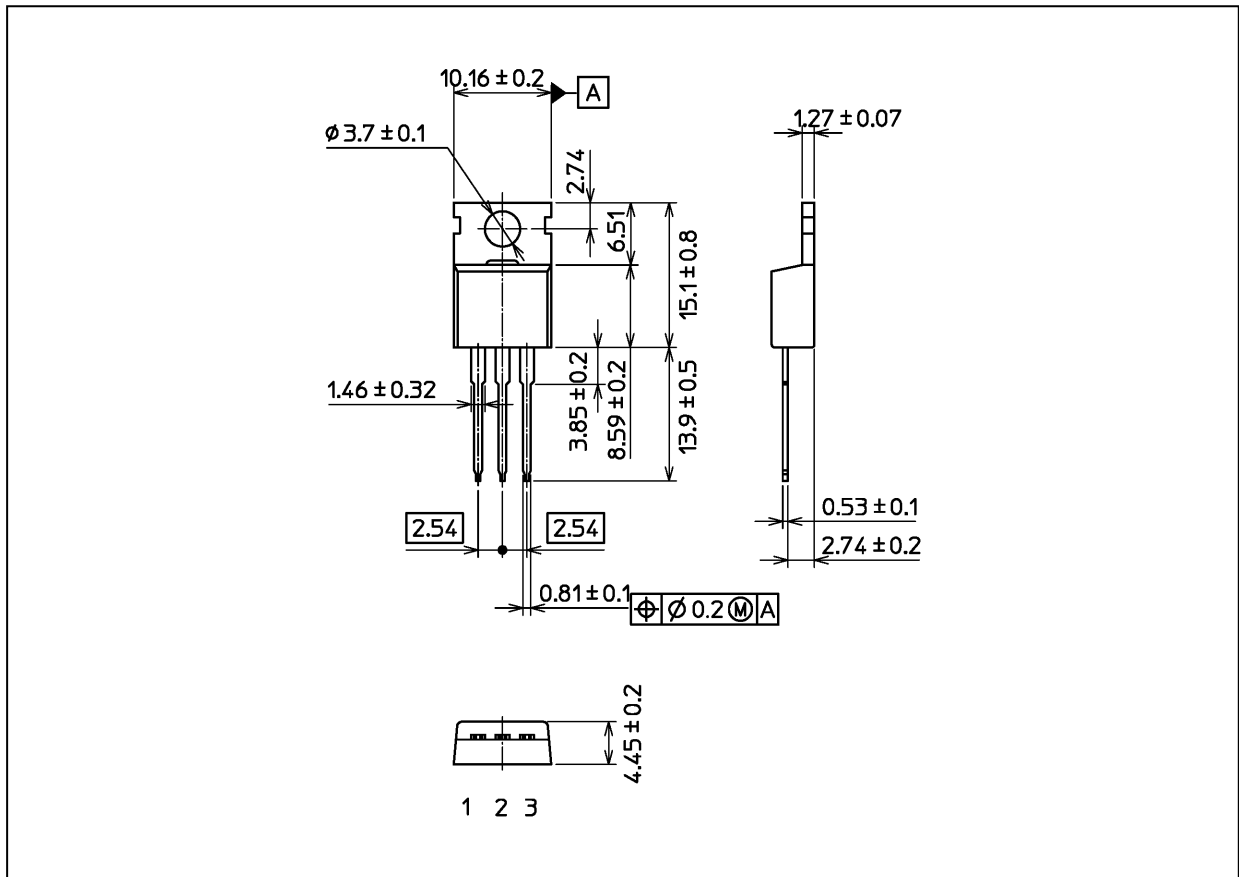


**Fig. 8.13 Safe Operating Area  
(Guaranteed Maximum)**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 1.93 g (typ.)

Package Name(s)
TOSHIBA: 2-10X1A
Nickname: TO-220



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